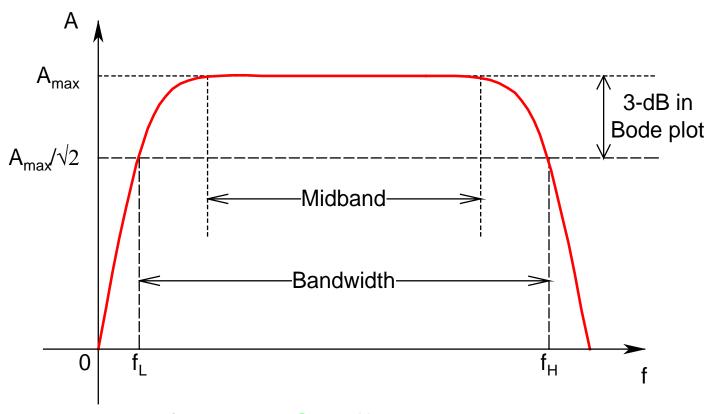
FREQUENCY RESPONSE

- So far, considered *midband analysis*, where *all capacitive effects were neglected*
 - > Voltage/current gain was independent of frequency
- In *practical amplifier circuits*, however, the *gain would depend on frequency*
- Characterized by:
 - > Lower Cutoff Frequency (f_I)
 - Contributed by external capacitors (C_E, C_B, C_C)

- **► Upper Cutoff Frequency** (f_H)
 - Contributed by device capacitances (for BJTs: C_{π} , C_{μ} ; for MOSFETs: C_{gs} , C_{gd} , C_{sb} , C_{db})
- These capacitors create *charge storage effects*, and *introduce time constants* into
 the circuit
- Discrete circuits show both f_L and f_H
- IC stages show only f_H , since most of them are direct coupled without the need for any external capacitors



f_L: Lower Cutoff Frequency **f**_H: Upper Cutoff Frequency

Bandwidth = $f_H - f_L$

- Exact analysis extremely complicated
 - ➤ Most often, results in *very complicated expressions*, *completely hiding the physical feel of the phenomenon*
 - > Makes debugging extremely difficult
 - For example, a circuit having *4 capacitors*, will have a *fourth-order transfer function*, which needs to be *solved* to get all the *poles and zeros* of the system
 - ➤ However, there are *techniques*, which make these *analyses* extremely *trivial*
 - Not accurate, but extremely simple, and makes debugging easy

• Techniques:

- ➤ Infinite-Value Time Constant (IVTC) Method
 - Used for obtaining f_L
- > Zero-Value Time Constant (ZVTC) Method
 - Used for obtaining f_H
- These techniques are *extremely easy to* apply, and the results are *quite close to* actuals
- However, there is *one limitation* of these techniques

- They give information only regarding the *Dominant Pole* (DP) of the circuit
- Completely hides information about other poles and zeros of the circuit [known as Non-Dominant Poles (NDP) or Zeros (NDZ)]
- Anyway, information about *NDP and NDZ* are *not* that *critically important* from *practical point of view*

Low-Frequency Response

- The Infinite-Value Time Constant (IVTC) Technique:
 - ➤ Used for obtaining the *lower cutoff frequency* (f_I)
 - ➤ If a circuit has *n* number of *capacitors*, then it would have *n* number of *time constants*
 - \succ This technique derives the information regarding f_L from these time constants

• The Algorithm:

- > Null all independent sources to the circuit
 - Short all independent voltage sources
 - Open all independent current sources
 - DO NOT TOUCH DEPENDENT SOURCES
- \triangleright Name the capacitors C_i (i = 1-n)
- ➤ Consider C₁ and assign infinite values to all other capacitors (thus the name!)
 - Thus, $except C_1$, all other capacitors will short out
- ► Determine the Thevenin Resistance (R_1^{∞}) across the two terminals of C_1

- Find the time constant τ_1 associated with C_1 $\left(\tau_1 = R_1^{\infty} C_1\right)$
- ightharpoonup Calculate the corresponding frequency $f_1 = 1/(2\pi\tau_1)$
- Repeat for all other capacitors, taking one at a time, and find all the rest of the frequencies $(f_2, f_3, ..., f_n)$
- Then the *Lower Cutoff Frequency* f_L can be expressed as:

$$\mathbf{f}_{L} = \left[\sum_{i=1}^{n} \mathbf{f}_{i}^{2}\right]^{1/2}$$

- In discrete circuits, a major component of total cost is due to the cost of the capacitors (directly proportional to the value)
- Hence, an attempt is made to *minimize* the *total capacitor requirement of the circuit*
- For this, the *Dominant Pole* (DP) technique is used
 - \triangleright One of the frequencies among f_1 - f_n is made dominant
 - > Others are made to lie at least 10 times away from it

For example, if f_d is chosen to be the DP, then all other poles are assumed to be at $f_d/10$

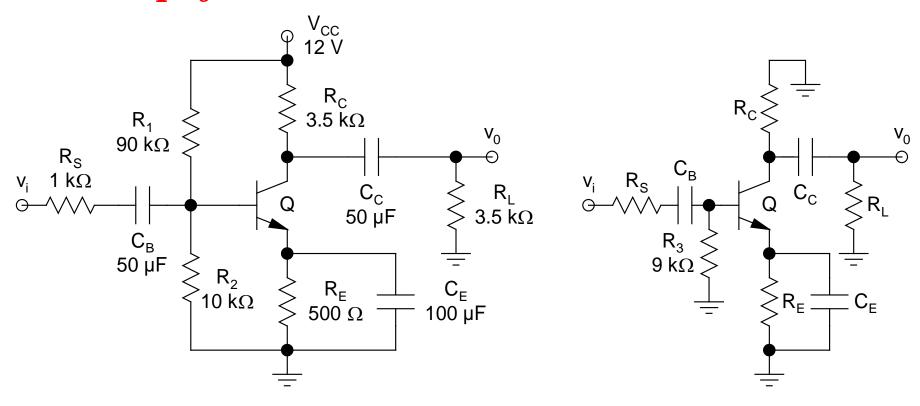
$$\Rightarrow f_{L} = \left[f_{d}^{2} + \sum_{n-1} \left(\frac{f_{d}}{10} \right)^{2} \right]^{1/2}$$

 \succ C_d , which *contributes* f_d , is *chosen* to be that capacitor that *sees* the *least Thevenin resistance* across its terminals

> Reason is obvious:

- If *any other capacitor* were *chosen* to *contribute* f_d, then C_d would have been *ten times higher*
- > This choice is based on heuristics

• Low-Frequency Response of RC-Coupled Amplifier:



Complete Circuit

ac Schematic

- ightharpoonup DC analysis gives $I_C = 1$ mA and $V_{CE} = 4$ V $\Rightarrow r_E = 26$ Ω and $r_\pi = 2.6$ kΩ (assuming $\beta = 100$)
- > Neglect Early effect $\Rightarrow r_0 \rightarrow \infty$
- ➤ 3 capacitors (C_B , C_E , C_C) with time constants τ_1 , τ_2 , τ_3 , and corresponding cutoff frequencies f_1 , f_2 , f_3
- To apply the *IVTC technique*, we have to take one capacitor at a time and treat other capacitors as short circuits
- > The analysis can be done by inspection!

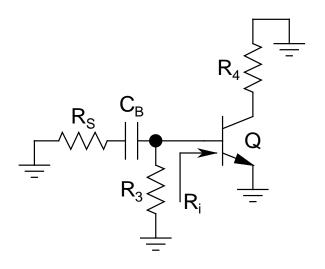
$> C_B$

- Short C_C and C_E
- $R_3 = R_1 || R_2 = 9 \text{ k}\Omega$
- $R_4 = R_C || R_L = 1.75 \text{ k}\Omega$
- $R_i = r_{\pi} = 2.6 \text{ k}\Omega$
- By inspection, the *Thevenin resistance* seen by C_B:

$$R_{\rm B}^{\infty} = R_{\rm S} + (R_3 || R_{\rm i}) = 3 \text{ k}\Omega$$

$$\Rightarrow \tau_1 = R_B^{\infty} C_B = 150 \text{ ms}$$

$$\Rightarrow$$
 f₁ = 1/(2 π τ ₁) = 1.06 Hz

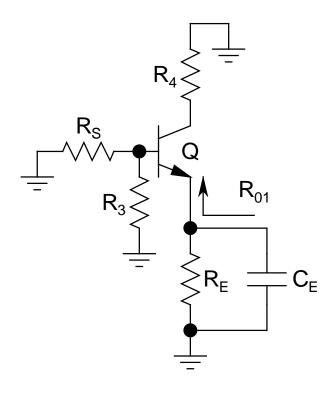


$\succ C_E$:

- Short C_C and C_B
- $R_{01} = r_E + (R_S || R_3)/(\beta + 1)$ = 34.9 Ω
- By inspection, the *Thevenin resistance* seen by C_E:

$$R_E^{\infty} = R_E || R_{01} = 32.6 \Omega$$

 $\Rightarrow \tau_2 = R_E^{\infty} C_E = 3.26 \text{ ms}$
 $\Rightarrow f_2 = 1/(2\pi\tau_2) = 48.8 \text{ Hz}$



$> C_C$:

- Short C_E and C_B
- By inspection, the *Thevenin resistance* seen by C_C :

$$R_C^{\infty} = R_C + R_L = 7 \text{ k}\Omega$$

 $\Rightarrow \tau_3 = R_C^{\infty} C_C = 350 \text{ ms}$

$$\Rightarrow$$
 f₃ = 1/(2 π \tau₃) = 0.45 Hz

■ Thus, the *lower cutoff frequency* of the circuit:

$$f_{L} = \left[f_{1}^{2} + f_{2}^{2} + f_{3}^{2}\right]^{1/2} = 48.8 \text{ Hz}$$

- \triangleright Note that f_L is equal to f_2 (contributed by C_E)
- > Now let's attempt to *minimize* the *total* capacitance requirement of the circuit

> Minimization of the Total Capacitance:

- From the previous analysis, we note that C_E sees the least Thevenin resistance across its two terminals
 - \Rightarrow Let's choose C_E to contribute the $DP f_d$, and let C_C and C_B each contribute poles at $f_d/10$

$$\Rightarrow 48.8 = \sqrt{f_d^2 + 2(f_d/10)^2}$$

$$\Rightarrow$$
 f_d = 48.3 Hz and f_d/10 = 4.83 Hz

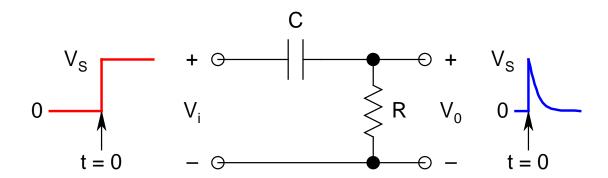
■ Thus:

$$C_{E} = 1/(2\pi f_{d}R_{E}^{\infty}) = 101.1 \mu F$$
 $C_{B} = 1/[2\pi (f_{d}/10)R_{B}^{\infty}] = 11 \mu F$
 $C_{C} = 1/[2\pi (f_{d}/10)R_{C}^{\infty}] = 4.7 \mu F$

- Thus, the *total capacitance* requirement comes out to be $116.8 \mu F$, for the *same* f_L of 48.8 Hz
- The original circuit had a total capacitance of 200
 μF
- Thus, this approach gave a *cost saving* of almost
 42% in terms of the *capacitors*
- As an *exercise*, you can pick *either* C_C *or* C_B to *contribute* f_d , and find the *total capacitance* requirement for each case
- Finally, after all, this is a *heuristic*
- To get the *absolute minimum value* of the *total* capacitance, we need to *formulate the problem*, and find the minima of the function mathematically

• Tilt/Sag:

- For *pulse/square wave excitation*, f_L dictates the amount of *tilt/sag* present in the *output*
- \triangleright Due to f_L , the circuit effectively behaves like a HPF, represented by a simple RC circuit
- ➤ Under *step input*, the *output* would be a *spike*



> Thus:

$$V_0 = V_S \exp(-t/\tau_L)$$

$$\tau_L = RC = 1/\omega_L \quad (\omega_L = 2\pi f_L)$$

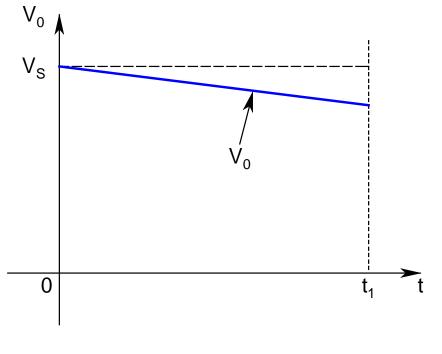
 \triangleright For t << τ_L :

$$V_0 \approx V_S (1 - t/\tau_L)$$

$$= V_S (1 - \omega_L t)$$

$$= V_S (1 - 2\pi f_L t)$$

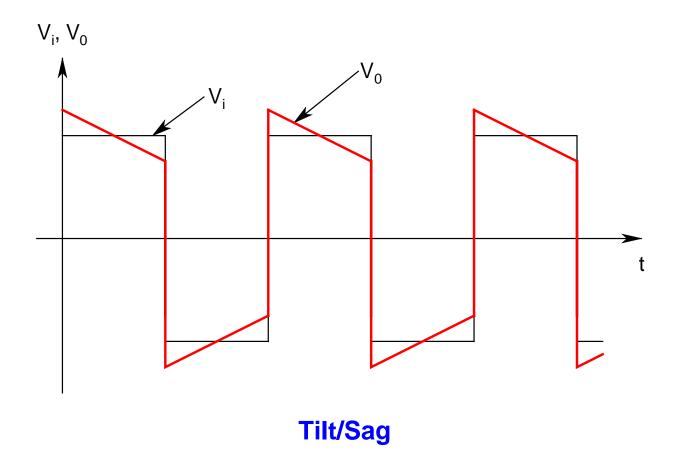
- \succ Thus, V_0 drops linearly with time
- > Quantified by percent tilt/sag (P)



- $P = [(V_S V_0)/V_S] \times 100\%$ $= (t_1/\tau_L) \times 100\%$
 - $t_1 = Time at which the tilt is measured$
- For square wave input, $t_1 = T/2$ (T = period = 1/f, f = cycle frequency)

$$\Rightarrow P = [T/(2\tau_L)] \times 100\% = [\omega_L/(2f)] \times 100\%$$
$$= (\pi f_L/f) \times 100\%$$

- \succ Note: P is directly proportional to f_L and inversely proportional to f
 - \Rightarrow Circuits having low f_L , will show significant amount of tilt/sag at low frequencies

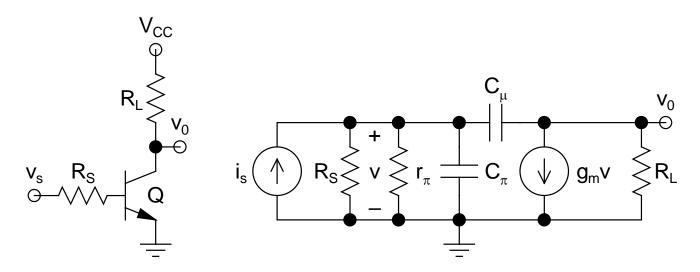


High-Frequency Response

- Will consider 3 methods:
 - > Exact Analysis:
 - The *most accurate* and the *most rigorous*
 - Gives information about all poles and zeros of the system
 - ➤ Miller Effect Approximation:
 - One level of approximation
 - Gives information about the Dominant Pole (DP) and one Non-Dominant Pole (NDP)

- > Zero-Value Time Constant (ZVTC)
 Technique:
 - **The easiest one**
 - Information regarding only the DP
 - Suppresses information about all other poles and zeros of the system
 - Reasonable accuracy
 - Underestimates f_H slightly (better than overestimating and not achieving it!)
 - Based on heuristic
 - Similar to the IVTC technique, based on an algorithm

• Exact Analysis of a CE Stage:



ac Schematic

High-Frequency Equivalent

- > Biasing circuits omitted for simplicity
- \triangleright Converted input v_s to its Norton equivalent

> KCL at input node (using Laplace operator s

=
$$j\omega$$
 and $R = R_S || r_{\pi}$):

$$i_s = v/R + sC_{\pi}v + sC_{\mu}(v - v_0)$$

= $[1/R + s(C_{\pi} + C_{\mu})]v - sC_{\mu}v_0$

> KCL at output node:

$$sC_{\mu}(v_0 - v) + g_m v + v_0 / R_L = 0$$

$$\Rightarrow v = -\frac{1/R_L + sC_{\mu}}{g_m - sC_{\mu}} v_0$$

$$\Rightarrow \frac{V_0}{i_s}(s) = -\frac{R_L R (g_m - sC_\mu)}{1 + s(R_L C_\mu + RC_\mu + RC_\pi + g_m R_L RC_\mu) + s^2 R_L RC_\pi C_\mu}$$

Thus, the *voltage gain*:

$$A_{v}(s) = \frac{v_{0}}{v_{s}} = -\frac{g_{m}R_{L}R}{R_{S}} \frac{\left(1 - sC_{\mu}/g_{m}\right)}{1 + sa + s^{2}R_{L}RC_{\pi}C_{\mu}}$$
(1)

$$a = R_L C_{\mu} + R(C_{\pi} + C_{\mu}) + g_m R_L RC_{\mu}$$

➤ Hence, the circuit has *one zero* and *two poles*

$$\Rightarrow A_{v}(s) = A_{v0} \frac{(1-s/z_{1})}{(1-s/p_{1})(1-s/p_{2})}$$
 (2)

$$A_{v0} = midband gain = -g_m R_L R/R_S$$
$$= -g_m R_L r_\pi/(r_\pi + R_S)$$

- $\geq z_1 = g_m/C_u$: positive real zero
- The *frequency* corresponding to z_1 occurs at $z_1/(2\pi)$, which is *extremely high*, and generally, is *not of much consequence*
- \succ Computation of the two poles p_1 and p_2 is slightly more tricky
- From Eqs.(1) and (2), it is obvious that both p_1 and p_2 are real and negative

To find these, write the denominator of Eq.(1) as:

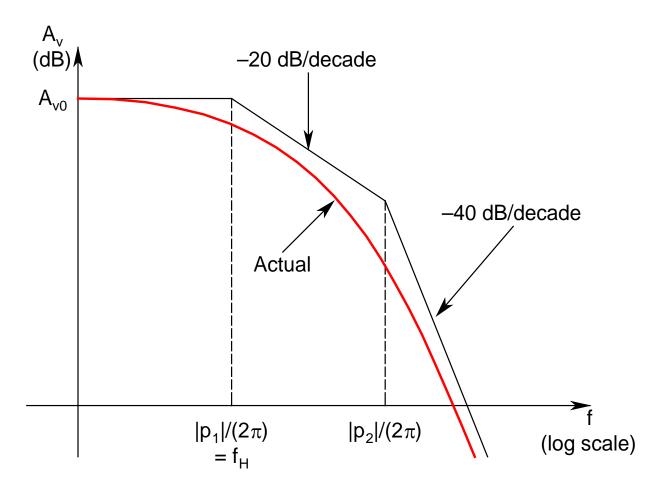
$$D(s) = (1 - s/p_1)(1 - s/p_2)$$

$$= 1 - s(1/p_1 + 1/p_2) + s^2/(p_1p_2)$$
(3)

- ightharpoonup Matching coefficients with Eq.(2), we can get p_1 and p_2 , however, the resulting algebra will become extremely tedious
- ➤ Hence, we invoke the *Dominant Pole Approximation* (DPA)

> **DPA**:

- The smallest pole [Dominant Pole (DP)] is at least 10 times away from its nearest pole
- This is an excellent approximation for practical analog circuits
- ➤ Apply this approximation and assume p₁ to be the DP and at least 10 times away from p₂
 [Non-Dominant Pole (NDP)]
- ightharpoonup The *pole frequencies* are $|p_1|/(2\pi)$ and $|p_2|/(2\pi)$
- Note: $|\mathbf{p}_1|/(2\pi)$ is the Upper Cutoff Frequency (\mathbf{f}_H)



Bode Plot of the Frequency Response of a 2-Pole System

- > 2-pole system
- For frequencies till the first pole p_1 , gain remains constant at its midband value of $20log_{10}A_{v0}$
- ➤ Beyond this, the gain rolls off at -20 dB/decade till the second pole p₂ is encountered
- ➤ After this, the gain rolls off at -40 dB/decade, and eventually crosses zero
- ➤ Beyond this, the circuit actually attenuates the input signal instead of amplifying it (gain magnitude drops below unity)

- \triangleright It's assumed that z_1 is $>> |p_2|$
- \triangleright Task remains to find p_1 and p_2
- > Under DPA, Eq.(2) can be simplified as:

$$D(s) \approx 1 - s/p_1 + s^2/p_1p_2 \tag{4}$$

> Comparing Eq.(4) with the denominator of Eq.(1):

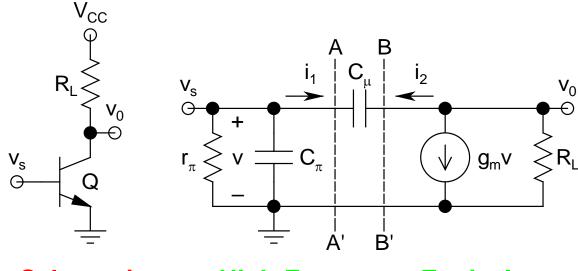
$$p_{1} = -\frac{1}{\left(R_{S} \| r_{\pi}\right) C_{\pi} + \left[\left(R_{S} \| r_{\pi}\right) + R_{L} + g_{m}\left(R_{S} \| r_{\pi}\right) R_{L}\right] C_{\mu}}$$

$$p_{2} = -\left(\frac{1}{R_{L}C_{\mu}} + \frac{1}{\left(R_{S} \| r_{\pi}\right) C_{\pi}} + \frac{1}{R_{L}C_{\pi}} + \frac{g_{m}}{C_{\pi}}\right)$$

- \triangleright In general, $|p_2| >> |p_1|$
- $Ex.: I_C = 1 \text{ mA}, \beta = 200, R_S = 1 \text{ k}\Omega, R_L = 2 \text{ k}\Omega, C_{\pi} = 10 \text{ pF}, C_{\mu} = 0.5 \text{ pF}$
 - \Rightarrow **DPF** = 3.8 MHz, **NDPF** = 798.8 MHz, **ZF** = 12.3 GHz, and $f_H = DPF = 3.8$ MHz
- > Note: Even for a simple CE circuit, the analysis is so cumbersome, and the results are so complicated
- Definitely not acceptable for routine application, particularly for circuits having more than one active device

• Miller Effect Approximation:

- Technique by which an input-output coupled circuit can be decoupled by removing the coupling element
- This *removal* is done by *splitting* it into *two* components putting one in the input circuit, and the other in the output circuit
- We take the *same example* as the *CE circuit* discussed earlier, but now *without* R_S



ac Schematic

High-Frequency Equivalent

- ► Identify C_{μ} as the input-output coupling element
- After application of the technique, this coupling element will be removed by splitting it into two parts one at input, other at output

- These *two parts* can be found by *evaluating* the *impedances* looking into the *planes* AA' and BB'
- > KCL at output node:

$$g_{\rm m}v + v_0/R_{\rm L} + sC_{\mu}(v_0 - v) = 0$$

 \triangleright Noting that $v = v_s$, the *voltage gain*:

$$A_{v}(s) = v_{0}/v_{s} = -g_{m}R_{L}(1 - sC_{\mu}/g_{m})/(1 + sR_{L}C_{\mu})$$

⇒ Midband or low-frequency gain:

$$A_{v}(0) = -g_{m}R_{L}$$

This result can also be written from inspection

> Current entering plane AA':

$$i_1 = sC_{\mu}(v - v_0) = sC_{\mu}[1 - A_{\nu}(s)]v$$

➤ Hence, the *admittance* looking into the *plane* AA':

$$y|_{AA'} = i_1/v = sC_{\mu} [1 - A_{\nu}(s)]$$

This *admittance* is *capacitive* in nature, and is known as the *Miller Capacitance* C_M :

$$C_{\mathrm{M}} = C_{\mu}[1 - A_{\mathrm{v}}(\mathrm{s})]$$

Now, since $A_{\nu}(s)$ is a function of frequency, so would $C_M \Rightarrow Problem!$

- ➤ Here, we invoke the *Miller Effect Approximation* (MEA)
 - $A_{\nu}(s)$ is replaced by $A_{\nu}(0)$, i.e., by its midband value, which is a constant
 - Thus, C_M becomes a constant with a value of $C_M = [1 A_v(0)]C_{\mu} = (1 + g_m R_L)C_{\mu}$
- \gt Thus, $C_M >> C_\mu$, since, in general, $g_m R_L >> 1$
- This effect is known as the *Miller Effect Multiplication*
- \succ Care: The gain that multiplies C_{μ} is across its two ends

> Similarly, *current entering plane BB* ':

$$i_2 = sC_{\mu}(v_0 - v) = sC_{\mu}[1 - 1/A_{\nu}(s)]v_0$$

➤ Hence, the *admittance* looking into the *plane* BB':

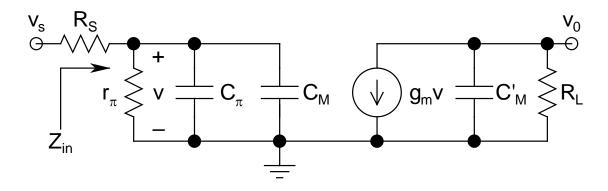
$$y'|_{BB'} = i_2/v_0 = sC_{\mu}[1-1/A_{\nu}(s)]$$

Again *replacing* $A_v(s)$ by $A_v(0)$, we get:

$$C'_{M} = [1-1/A_{v}(0)]C_{\mu} = [1+1/(g_{m}R_{L})]C_{\mu}$$

$$ightharpoonup$$
In general, $g_m R_L >> 1 \implies C'_M \simeq C_\mu$

- $ightharpoonup C_{\mu}$ can now be *removed* as the *coupling* element, split into 2 parts C_M and C_M' , with C_M appearing in the *input circuit* and C_M' appearing in the *output circuit*
- Now, include R_S note that the circuit is completely decoupled now



Complete Circuit Including R_s

$$\begin{split} & > Z_{in} = r_{\pi} || [1/(sC_{T}) = r_{\pi}/(1 + sr_{\pi}C_{T}) \\ & C_{T} = C_{\pi} + C_{M} \\ & \Rightarrow v = \frac{Z_{in}}{Z_{in} + R_{S}} v_{s} \\ & = \frac{r_{\pi}}{\left(R_{S} + r_{\pi}\right) \left[1 + sr_{\pi}R_{S}C_{T}/\left(R_{S} + r_{\pi}\right)\right]} v_{s} \\ & v_{0} = -g_{m} \left(R_{L} || \frac{1}{sC_{M}'}\right) v = -\frac{g_{m}R_{L}}{1 + sR_{L}C_{M}'} v \end{split}$$

> Thus:

$$\mathbf{A}_{\mathbf{v}}\left(\mathbf{s}\right) = \frac{\mathbf{v}_{0}}{\mathbf{v}_{\mathbf{s}}}$$

$$= -g_{m}R_{L}\frac{r_{\pi}}{R_{S} + r_{\pi}}\frac{1}{\left[1 + sR_{S}r_{\pi}C_{T}/(R_{S} + r_{\pi})\right](1 + sR_{L}C_{M}')}$$

> Comparing this expression with

$$A_{v}(s) = \frac{A_{v0}}{(1-s/p_{1})(1-s/p_{2})}$$

we note that the *denominator* is already in a *factorized form*

- > $A_{v0} = midband gain = -g_m R_L r_{\pi}/(R_S + r_{\pi})$
- The *transfer function* shows that the system has *two negative real poles* and *no zero*
 - ⇒ Information regarding the zero is suppressed by this technique
- Also, the *two poles* obtained by *this technique* are *not identical* to those obtained from the *exact analysis*

- ➤ Pole p₁ (p₂) is referred to as the pole of the input (output) circuit
- ➤ Also, $|\mathbf{p}_1| << |\mathbf{p}_2|$ ⇒ p_1 (p_2) is the DP (NDP) of the system
- > Matching coefficients:

$$p_{1} = -\frac{R_{S} + r_{\pi}}{R_{S} r_{\pi}} \frac{1}{C_{T}} = -\frac{1}{(R_{S} || r_{\pi}) [C_{\pi} + (1 + g_{m} R_{L}) C_{\mu}]}$$

$$p_{2} = -\frac{1}{R_{L} C_{M}'}$$

 \triangleright Obviously, $|p_1| \ll |p_2|$

- ightharpoonup Thus, using DPA: $f_H = |p_1|/(2\pi)$
- Applying this technique to the previous example, $f_H = 3.9 \text{ MHz}$ and NDP frequency = 156 MHz
 - Error of only 2.6% in f_H , but the ease of solution is much more
- Thus, this technique is quite popular in getting a quick estimate of f_H, even though the solution may not be exact
- Care: The gain in the multiplicative factor is that between the input and output terminals of the capacitor

- The Zero-Value Time Constant (ZVTC) Technique:
 - ➤ Gives information only about the DP of the system
 - > Suppresses all information regarding other poles and zeros
 - The ease of application of this technique is mind-boggling

- > Slightly less accurate
- > The maximum error can be as high as 22%
- $Underestimates f_H$
 - Far better than overestimation and eventually not achieving it
- > Applicable only for circuits that have a DP
 - Fortunately, almost all analog circuits of interest do have a DP

• The Algorithm:

- > Null all independent sources to the circuit
 - Short all independent voltage sources
 - Open all independent current sources
 - DO NOT TOUCH DEPENDENT SOURCES
- \triangleright Name the capacitors C_i (i = 1-n)
- ➤ Consider C₁ and assign zero values to all other capacitors (thus the name!)
 - Thus, except C_1 , all other capacitors will open out
- ► Determine the Thevenin Resistance (R_1^0) across the two terminals of C_1

- Find the time constant τ_1 associated with C_1 $\left(\tau_1 = R_1^0 C_1\right)$
- Repeat for all other capacitors, taking one at a time, and find all the rest of the time constants $(\tau_2, \tau_3, ..., \tau_n)$
- \triangleright Determine the *net time constant* τ_{net} by *summing up* all the *individual time constants*

$$\Rightarrow au_{\text{net}} = \sum_{i=1}^{n} au_{i}$$

Then the *Upper Cutoff Frequency* f_H is simply given by: $f_H = 1/(2\pi\tau_{net})$

- \triangleright Note: The capacitor contributing the largest time constant, in effect, determines f_H
- > The technique suppresses all information regarding other poles and zeros
- ➤ Will present *several examples* to understand the *application* of this *technique*
- Some *topologies* will be appearing *frequently*, known as *Standard Forms*, which can be treated as *individual modules*, and the *results* can be used freely

• *CE*:

- Refer to the *high-frequency equivalent* given in the *exact analysis*
- \triangleright 2 capacitors: C_{π} and C_{μ}
 - \Rightarrow 2 time constants: τ_1 and τ_2
- $> C_{\pi}$
 - C_{μ} opens up
 - **By inspection:**

$$R_{\pi}^{0} = R_{S} \parallel r_{\pi}$$

$$\Rightarrow \tau_{1} = R_{\pi}^{0} C_{\pi}$$

$> C_{\mu}$

- \blacksquare C_{π} opens up
- This is one *Standard Form*,
 known as the *Three*-

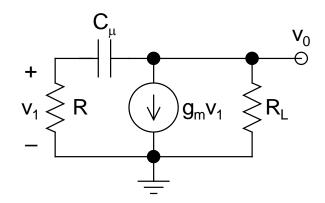
Legged Creature

Show that:

$$R_{\mu}^{0} = R + R_{L} + g_{m}R_{L}R \qquad (R = R_{S} \parallel r_{\pi})$$

$$\Rightarrow \tau_{2} = R_{\mu}^{0}C_{\mu}$$

- \succ Thus, $\tau_{\text{net}} = \tau_1 + \tau_2$, and $f_H = 1/(2\pi\tau_{\text{net}})$
- > Note the *amazing simplicity* of the analysis



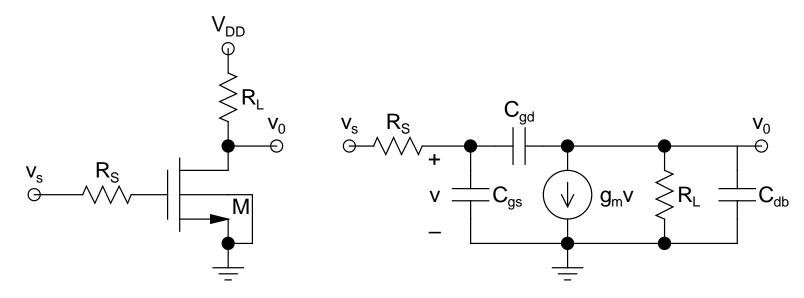
> Putting *values* of our previous *example*:

$$R_{\pi}^{0} = 838.7 \ \Omega, \ \tau_{1} = 8.4 \ ns$$

 $R_{\mu}^{0} = 67.4 \ k\Omega, \ \tau_{2} = 33.7 \ ns$
 $\Rightarrow \tau_{net} = 42.1 \ ns \ and \ f_{H} = 3.8 \ MHz$

- This is *identical* to the *result* obtained from the *exact analysis*, however, at a *fraction* of the *effort*!
- Also, τ_2 is the dominant time constant $\Rightarrow f_H$ is primarily dictated by C_μ

• *CS*:



ac Schematic

High-Frequency Equivalent

 $\succ C_{sb}$ absent (Why?)

- \triangleright 3 capacitors: C_{gs} , C_{gd} , and C_{db}
 - \Rightarrow 3 time constants: τ_1 , τ_2 , and τ_3
- $\succ C_{gs}$:
 - C_{gd} and C_{db} open up
 - **By inspection:**

$$R_{gs}^0 = R_{s}$$

$$\Rightarrow \tau_1 = R_{gs}^0 C_{gs}$$

- $> C_{gd}$:
 - C_{gs} and C_{db} open up
 - By inspection, it can be identified as a Three-Legged Creature

■ Thus:

$$R_{gd}^{0} = R_{S} + R_{L} + g_{m}R_{S}R_{L}$$
$$\Rightarrow \tau_{2} = R_{gd}^{0}C_{gd}$$

- $> C_{db}$:
 - C_{gs} and C_{gd} open up
 - **By inspection:**

$$R_{db}^{0} = R_{L}$$

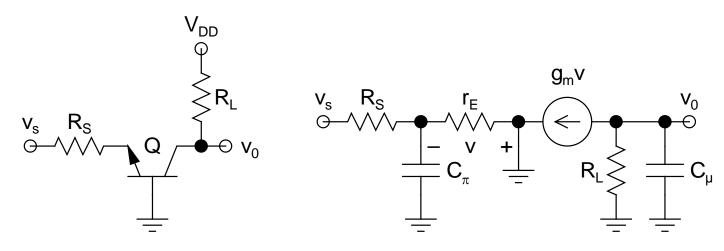
$$\Rightarrow \tau_{3} = R_{db}^{0} C_{db}$$

> Thus:

$$\tau_{\text{net}} = \tau_1 + \tau_2 + \tau_3$$
, and $f_{\text{H}} = 1/(2\pi\tau_{\text{net}})$

> Mind-bogglingly simple - isn't it?

• *CB*:



ac Schematic

High-Frequency Equivalent

- Note that there is no input-output coupling capacitor present in this circuit
 - \Rightarrow Miller effect will be absent, and the circuit will have very high f_H

$$\succ C_{\pi}$$

$$R_{\pi}^{0} = R_{S} \parallel r_{E}$$
 and $\tau_{1} = R_{\pi}^{0}C_{\pi}$

 $> C_{\mu}$:

$$R_{\mu}^{0} = R_{L}$$
 and $\tau_{2} = R_{\mu}^{0}C_{\mu}$

Taking the *values* of our previous *example*:

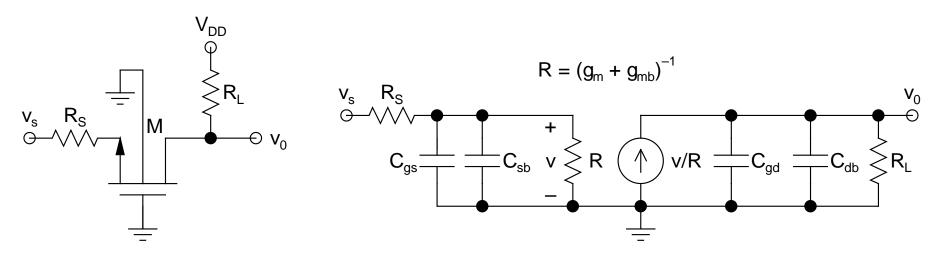
$$R_{\pi}^{0} = 25.34 \ \Omega, \ \tau_{1} = 0.253 \ ns$$

$$R_{\mu}^{0} = 2 \text{ k}\Omega, \ \tau_{2} = 1 \text{ ns}$$

$$\Rightarrow \tau_{net} = 1.25 \text{ ns} \text{ and } f_H = 127.3 \text{ MHz}$$

 \triangleright Note the enormous increase of f_H from about 4 MHz, for a CE amplifier

• CG:



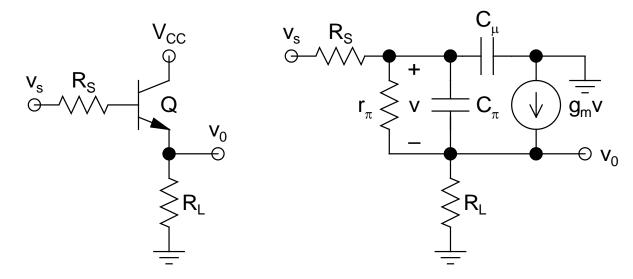
ac Schematic

High-Frequency Equivalent

➤ Note that all 4 capacitors would be present and none could be eliminated

- $\succ C_{gs}$ and C_{sb} are in parallel
 - \Rightarrow Can be clubbed to a single capacitor $C_1 = C_{gs} + C_{sb}$, with time constant τ_1
- Also, C_{gd} and C_{db} can be clubbed to another single capacitor $C_2 = C_{gd} + C_{db}$, with time constant τ_2
- > Again note the absence of any input-output coupling capacitor
 - \Rightarrow This circuit should also have very high f_H
- $ightharpoonup C_1$: $R_1^0 = R_S || R$ and $\tau_1 = R_1^0 C_1$
- $ightharpoonup C_2$: $R_2^0 = R_L$ and $\tau_2 = R_2^0 C_2$

• *CC*:



ac Schematic

High-Frequency Equivalent

- This circuit is slightly more involved can't be done by inspection
- > But we will have some other Standard Forms

- This circuit has a *peculiar frequency response*
 - At midband:

$$A_{v} = v_{0}/v_{s} = [R_{L}/(R_{L} + r_{E})] \times [R_{i}/(R_{i} + R_{S})]$$

$$R_{i} = r_{\pi} + (\beta + 1)R_{L}$$

- Beyond f_H , as $f \uparrow$, reactance of $C_{\pi} \checkmark$ earlier than that of C_{μ} (since, in general, $C_{\pi} >> C_{\mu}$)
- Eventually, reactance of C_{π} would approach zero, thus shorting out r_{π}
- Under this condition, circuit behaves like a *simple* voltage divider with a gain of $R_L/(R_L + R_S)$
- If f further, then eventually C_{μ} also will short out, and v_0 would go to zero

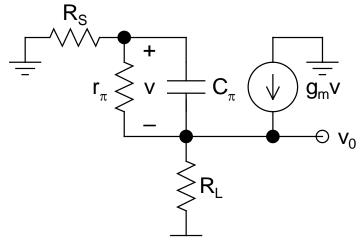
■ Thus, the *frequency response* of this circuit looks like a *staircase*, having *two steps*

$\succ C_{\pi}$

- \blacksquare R_{π}^{0} can't be obtained by inspection
- Analyze the circuit and show that:

$$R_{\pi}^{0} = r_{\pi} \parallel \left(\frac{R_{S} + R_{L}}{1 + g_{m}R_{L}} \right)$$

$$\Rightarrow \tau_{1} = R_{\pi}^{0}C_{\pi}$$



This is another Standard Form
 and the topology should be carefully noted

$\succ C_{\mu}$

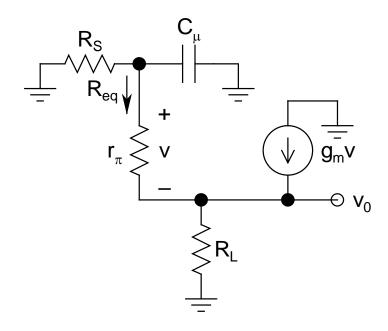
- This is relatively straightforward
- **By inspection:**

$$R_{eq} = r_{\pi} + (\beta + 1)R_{L}$$

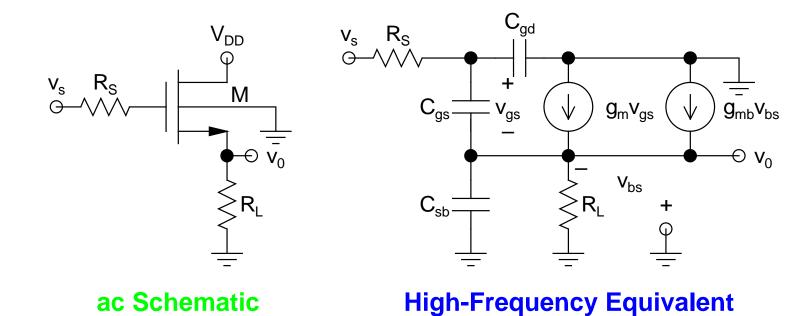
$$R_{\mu}^{0} = R_{S} || R_{eq}$$

$$\Rightarrow \tau_{2} = R_{\mu}^{0} C_{\mu}$$

This circuit also has reasonably good frequency response



• *CD*:



 $\succ C_{db}$ absent due to obvious reason

$$\triangleright v_{bs} = -v_0$$

 $\Rightarrow g_{mb}v_{bs}$ is simple a conductance g_{mb} , in parallel with R_L

$$\Rightarrow$$
 Club them to $R = R_L ||(1/g_{mb})|$

- $\succ C_{gs}$:
 - Standard Form sans $r_{\pi}(CC)$

$$\Rightarrow R_{gs}^{0} = \frac{R_{S} + R}{1 + g_{m}R}$$

$$\Rightarrow \tau_1 = R_{gs}^{0} C_{gs}$$

$\succ C_{gd}$:

By inspection:

$$R_{gd}^{0} = R_{S}$$

$$\Rightarrow \tau_{2} = R_{gd}^{0} C_{gd}$$

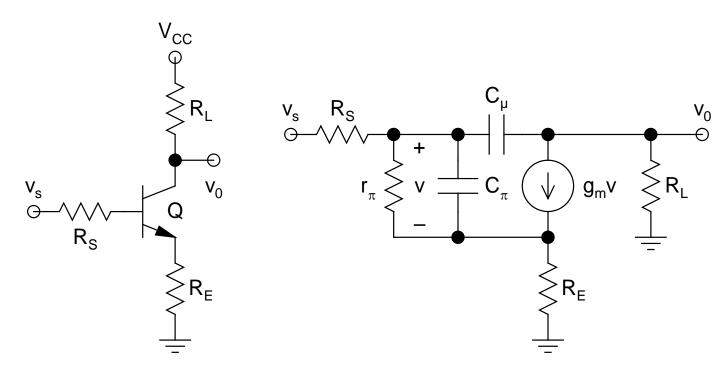
- $\succ C_{sb}$:
 - **By inspection**:

$$R_{sb}^{0} = R \parallel (1/g_{m})$$

$$\Rightarrow \tau_{3} = R_{sb}^{0} C_{sb}$$

> Loving it?:)

• *CE(D)*:



ac Schematic

High-Frequency Equivalent

$\succ C_{\pi}$

• Standard Form (similar to CC, with R_L replaced by R_E)

$$\Rightarrow R_{\pi}^{0} = r_{\pi} \parallel \left(\frac{R_{S} + R_{E}}{1 + g_{m}R_{E}} \right)$$
$$\Rightarrow \tau_{1} = R_{\pi}^{0}C_{\pi}$$

$> C_{\mu}$

- Slightly more complicated
- **Remove** C_{π} and look across 2 terminals of C_{μ}
- Can be represented by a 2-port network

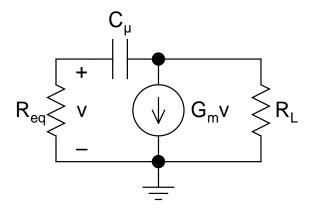
• Show that:

$$R_{eq} = R_S || R_{\pi}$$
with $R_{\pi} = r_{\pi} (1 + g_m R_E)$

$$G_m = g_m / (1 + g_m R_E)$$

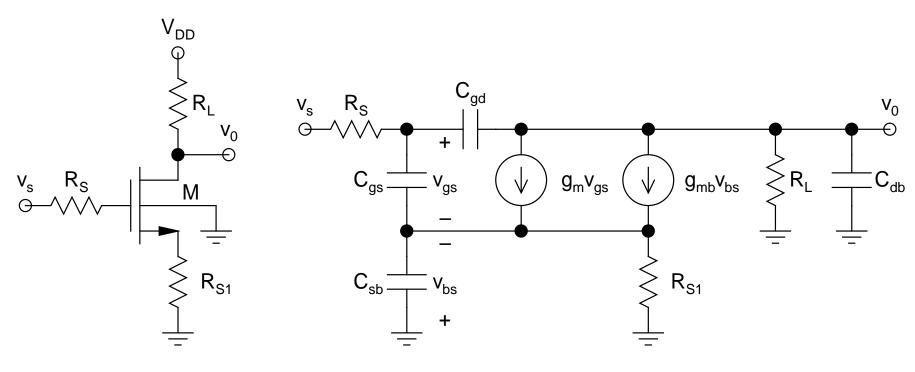
 This can be easily identified as a Three-Legged Creature

$$\Rightarrow R_{\mu}^{0} = R_{eq} + R_{L} + G_{m}R_{eq}R_{L}$$
$$\Rightarrow \tau_{2} = R_{\mu}^{0}C_{\mu}$$



2-Port Representation of a CE(D) Stage

• *CS(D)*:



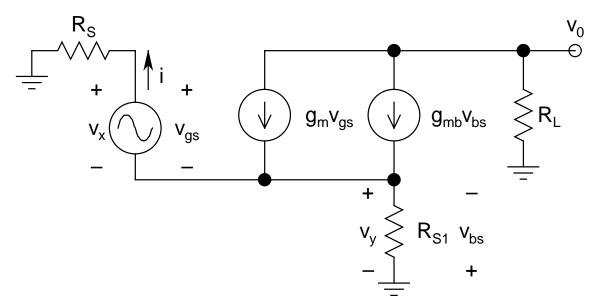
ac Schematic

High-Frequency Equivalent

> Inarguably, the most complex module

- All the capacitors will be present
- None will have Standard Form
- Detailed analysis needed for each of them

$$\succ C_{gs}$$
:



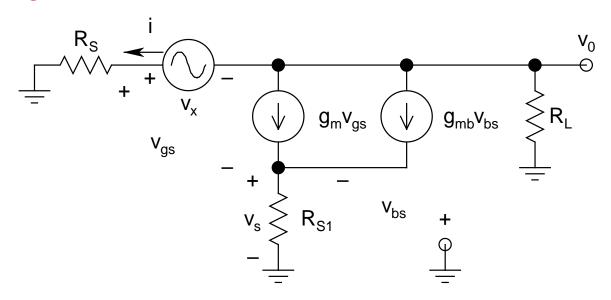
- Open all other capacitors
- Replace C_{gs} by a voltage source v_x

•
$$v_{gs} = v_x$$
 and $v_{bs} = -v_y$

$$\Rightarrow \tau_1 = R_{gs}^0 C_{gs}$$

■ Note that if body effect is neglected $(g_{mb} ignored)$, then it becomes identical to that of a CD stage

$> C_{gd}$:



- Open all other capacitors
- Replace C_{gd} by v_x
- $\mathbf{v}_{\mathrm{gs}} = (\mathbf{v}_0 + \mathbf{v}_{\mathrm{x}} \mathbf{v}_{\mathrm{s}}) \text{ and } \mathbf{v}_{\mathrm{bs}} = -\mathbf{v}_{\mathrm{s}}$

$$\bullet \quad i = (v_0 + v_x)/R_S$$

$$v_s = (g_m v_{gs} + g_{mb} v_{bs}) R_{S1}$$

$$\Rightarrow v_s = g_m R_{S1} (v_0 + v_x) / [1 + (g_m + g_{mb}) R_{S1}]$$

• KCL at output node:

$$i + g_m v_{gs} + g_{mb} v_{bs} + v_0 / R_L = 0$$

- The rest of the process involves huge amount of algebra!
- Finally, if done right (check!)

$$R_{gd}^{0} = \frac{v_{x}}{i} = R_{L} \left[1 + g_{m}R_{S} + \frac{R_{S}}{R_{L}} - \frac{(g_{m} + g_{mb})g_{m}R_{S}R_{S1}}{1 + (g_{m} + g_{mb})R_{S1}} \right]$$

$$\Rightarrow \tau_{2} = R_{gd}^{0}C_{gd}$$

- This is by far the most complicated calculation/expression
- However, an *exact analysis* would have yielded a 4th-order transfer function in ω, which had to be solved to get the *individual poles*
- This is still simpler than that :)

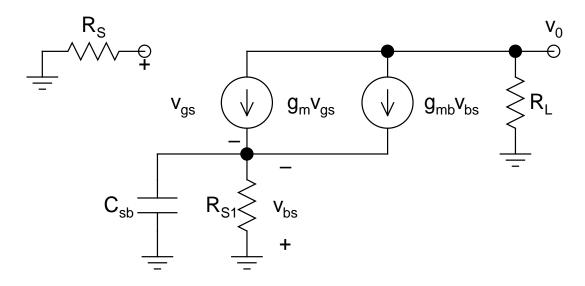
$\succ C_{db}$:

- The easiest of the lot
- **By inspection**:

$$R_{db}^{0} = R_{L}$$

$$\Rightarrow \tau_{3} = R_{db}^{0} C_{db}$$

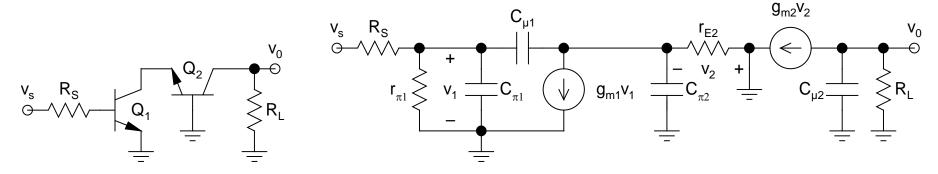
$> C_{sh}$:



Analysis of this circuit is pretty straightforward

$$R_{sb}^{0} = \frac{R_{S1}}{1 + (g_m + g_{mb})R_{S1}} \implies \tau_4 = R_{sb}^{0}C_{sb}$$

• npn Cascode:



ac Schematic

High-Frequency Equivalent

- Looks intimidating, but extremely easy to solve (just by inspection)
- ➤ Also known as *Wideband* (or *Broadband*) *Amplifier* due to its *superb frequency response*

> Reason:

- The circuit does have an input-output coupling capacitor (C_{u1})
- Miller Effect Multiplication Factor (MEMF) of $C_{\mu 1} = (1 A_{v1})$ $A_{v1} = voltage \ gain \ of \ Q_I = -r_{E2}/r_{E1} = -1$
 - (since Q_1 and Q_2 are biased with the same I_C)
 - \Rightarrow Thus, the *MEMF of C*_{μl} is only 2
- For *NMOS Cascode* stage, the *MEMF of C_{gd1}* of M_1 (*CS stage*) will be $[1 + 1/(1 + \chi_2)]$ (*verify this expression*), which is *even less than 2*

$\succ C_{\pi l}$:

By inspection:

$$R_{\pi 1}^{0} = R_{S} || r_{\pi 1} \implies \tau_{1} = R_{\pi 1}^{0} C_{\pi 1}$$

- $\succ C_{\mu l}$:
 - Can be easily identified as the *Three-Legged Creature*

$$\Rightarrow R_{\mu 1}^{0} = R_{\pi 1}^{0} + r_{E2} + g_{m1} R_{\pi 1}^{0} r_{E2}$$
$$\Rightarrow \tau_{2} = R_{\mu 1}^{0} C_{\mu 1}$$

- $\succ C_{\pi 2}$:
 - **By inspection**:

$$\mathbf{R}_{\pi 2}^{0} = \mathbf{r}_{E2} \quad \Rightarrow \mathbf{\tau}_{3} = \mathbf{R}_{\pi 2}^{0} \mathbf{C}_{\pi 2}$$

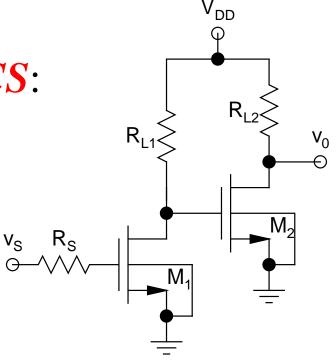
- $> C_{\mu 2}$:
 - **By inspection:**

$$R_{\mu 2}^{0} = R_{L} \quad \Rightarrow \tau_{4} = R_{\mu 2}^{0} C_{\mu 2}$$

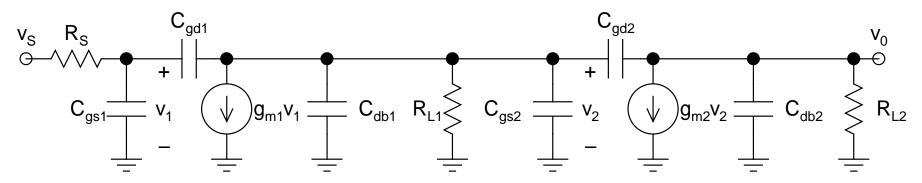
- Senerally, for this circuit, $C_{\pi 1}$ is the *dominant* capacitor that determines f_H , since it sees the largest resistance
- The resistance seen by $C_{\mu l}$, which is the largest for CE stage, becomes quite small here, due to the low gain of Q_1
- Note how *simple* it is to use this *technique* even for *multi-stage amplifiers*!

• NMOS 2-Stage Cascaded CS:

- Except C_{sb} , all other capacitors will be present for both devices
- > 6 capacitors
 - \Rightarrow 6 time constants



ac Schematic



High-Frequency Equivalent

- > Note: An exact analysis would have required solving a 6^{th} -order equation in ω !
- Let's perform a *quantitative analysis* of this circuit
- Data: $g_{m1} = 3 \text{ mA/V}$, $g_{m2} = 6 \text{ mA/V}$, $C_{gs1} = 5 \text{ pF}$, $C_{gs2} = 10 \text{ pF}$, $C_{gd1} = C_{gd2} = 1 \text{ pF}$, $C_{db1} = C_{db2} = 2 \text{ pF}$, $R_S = 10 \text{ kΩ}$, $R_{L1} = 10 \text{ kΩ}$, and $R_{L2} = 5 \text{ kΩ}$.
 - lacksquare C_{gs1} :

$$R_{gs1}^{0} = R_{S} = 10 \text{ k}\Omega \implies \tau_{1} = R_{gs1}^{0}C_{gs1} = 50 \text{ ns}$$

lacksquare C_{gd1} :

$$R_{gd1}^{0} = R_S + R_{L1} + g_{m1}R_SR_{L1} = 320 \text{ k}\Omega$$

 $\Rightarrow \tau_2 = R_{gd1}^{0}C_{gd1} = 320 \text{ ns}$

• C_{db1} and C_{gs2} in parallel

$$\Rightarrow$$
 Club them to a single capacitor $C_3 = C_{db1} + C_{gs2}$
= 12 pF

$$R_3^0 = R_{11} = 10 \text{ k}\Omega$$

$$\Rightarrow \tau_3 = R_3^0 C_3 = 120 \text{ ns}$$

lacksquare C_{gd2} :

$$R_{gd2}^{0} = R_{L1} + R_{L2} + g_{m2}R_{L1}R_{L2} = 315 \text{ k}\Omega$$

 $\Rightarrow \tau_4 = R_{gd2}^{0}C_{gd2} = 315 \text{ ns}$

■ C_{db2} :

$$R_{db2}^{0} = R_{L2} = 5 \text{ k}\Omega$$

$$\Rightarrow \tau_{5} = R_{db2}^{0} C_{db2} = 10 \text{ ns}$$

Thus:

$$\tau_{net} = 815 \text{ ns and } f_H = 195.3 \text{ kHz}$$

Such a low value of f_H is the result of the presence of a large number of capacitors in the circuit

- Limitations of the ZVTC Technique:
 - ➤ One obvious limitation is the suppression of information of all other poles and zeros of the system except the DP
 - This limitation is not that acute since we are actually interested in only the DP, which gives the information about f_H
 - The other limitation is the error, which can reach as high as 22%
 - ➤ However, *this error is negative*, i.e., *underestimation* (far better than *overestimation*)

- The *maximum error* of 22% occurs if the *actual circuit* has *two overlapping poles*
- In *real situations*, this is *highly unlikely*, due to the effect of *pole splitting* caused by *compensation* (*to be discussed in the next chapter*)
- The resulting circuit after compensation would have a single DP

> Proof that the maximum error is 22%

- Consider a circuit having 2 negative real poles at the same angular frequency ω_x
- The *Transfer Function*:

$$A(j\omega) = A_0/(1 + j\omega/\omega_x)^2$$

A₀: *Midband gain*

$$\Rightarrow |A(j\omega)| = A_0/[1 + (\omega/\omega_x)^2]$$

• At the upper cutoff frequency ω_H , the gain would drop to $1/\sqrt{2}$ of its maximum value

$$\Rightarrow 1 + (\omega_H/\omega_x)^2 = \sqrt{2}$$

$$\Rightarrow \omega_{\rm H} = [\sqrt{(\sqrt{2} - 1)}]\omega_{\rm x} = 0.64\omega_{\rm x}$$

 Now, using the ZVTC technique, the net time constant

$$\tau_{\text{net}} = \sum_{i=1}^{n} \left(-1/p_{i} \right)$$

i = number of poles

 $p_i = individual poles$

- For the *given problem*, i = 2 and $p_i = -\omega_x$ (*for both*)
- Thus:

$$\tau_{\rm net} = 2/\omega_{\rm x}$$
 and $\omega_{\rm H} = 1/\tau_{\rm net} = 0.5\omega_{\rm x}$

- Therefore, the *maximum error is about -22%*
- This being an underestimation, is not that dangerous:)

• Rise/Fall Time:

- ightharpoonup Recall: f_L caused tilt/sag in the output for square-wave input
- \triangleright On the other side of the frequency spectrum, f_H causes rise/fall time of the output for square-wave input
- These two phenomena can be thought of as an interlinking between the analog and digital domains
- Assume that a circuit has some ω_H , with the *corresponding pole* at $p_1 (= -\omega_H)$

> The *Transfer Function* is *single-pole*:

$$v_0(s)/v_i(s) = A_0/(1 - s/p_1)$$

A₀: Midband gain

Now, consider v_i to be **step input** of **amplitude** $V_A \implies v_i = V_A/s$

$$\Rightarrow v_0(s) = (A_0 V_A/s)/(1 - s/p_1)$$
$$= A_0 V_A [1/s - 1/(s - p_1)]$$

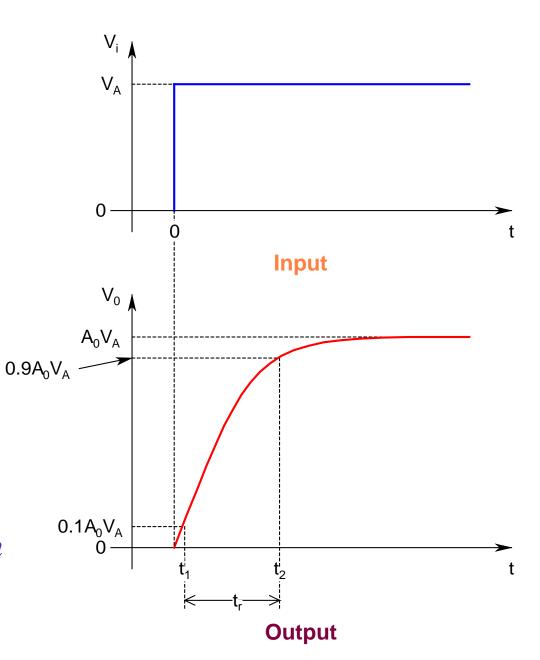
> Taking *inverse Laplace Transform*:

$$v_0(t) = A_0 V_A[1 - \exp(p_1 t)]$$

 \Rightarrow Output approaches its maximum value of A_0V_A with a time constant $1/|p_1|$ (p_1 negative)

> Calculation of Rise/Fall Time:

- Time taken
 for the output
 to rise (fall)
 from 10%
 (90%) to 90%
 (10%)
- Can be calculated from the figure



•
$$At t = t_1$$
:

$$0.1A_0V_A = A_0V_A[1 - \exp(p_1t_1)]$$

 $\Rightarrow t_1 = \ln(0.9)/p_1$

• $At t = t_2$:

$$0.9A_0V_A = A_0V_A[1 - \exp(p_1t_2)]$$

 $\Rightarrow t_2 = \ln(0.1)/p_1$

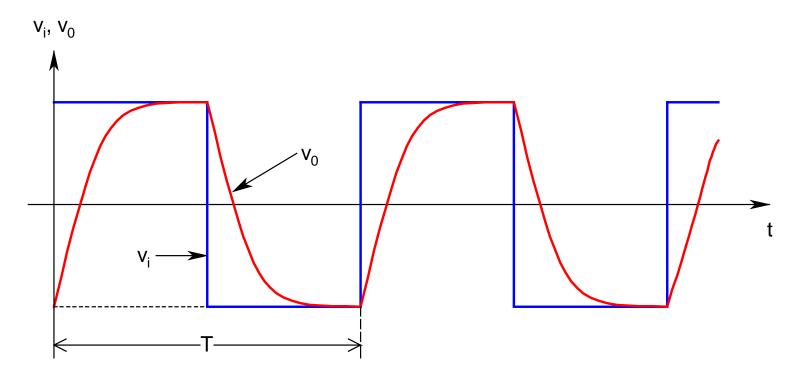
■ Thus, the *rise time*:

$$t_r = t_2 - t_1 = -2.2/p_1 = 2.2/\omega_H = 0.35/f_H$$

- Hence, higher the f_H , smaller the t_r
- The same expression holds for the fall time (t_f) as well

- Thus, circuits having high bandwidth under sinusoidal excitation (analog domain), will also have superb switching characteristics under square-wave excitation (digital domain)
- Under square-wave excitation, due to t_r/t_f , enough time should be provided for the transient in the output to get completed
- > Rule of Thumb:
 - At least 5 time constants should be allowed for each rising and falling transient
 - This determines the *maximum allowable frequency* of the *input pulse train*:

$$f_{\text{max}} = 1/T_{\text{min}} \approx 1/(10\tau) = \omega_H/10 = |p_1|/10$$



Effect of t_r/t_f on the Output for Square-Wave Excitation

➤ As $f \uparrow$, $T \downarrow$, V_0 first starts to become trianglular (incomplete transient), then the amplitude starts to drop, and eventually drops to zero (no output at all!)